

# SANYO Semiconductors **DATA SHEET**

**Monolithic Digital IC** 

# LB8681CL—Constant Current Driver IC with H-bridge × 1.5 Channel

#### Overview

The LB8681CL is a low-voltage, low-saturation 1.5-channel constant current forward/reverse driver IC provided in a miniature package suitable for use in cell phone cameras. The LB8681CL can be driven directly from a microcontroller and is optimal for control of the voice coil motors used for shutter and aperture control in cell phone cameras.

#### **Features**

- Supports low-voltage drive. (2.2V or more)
- Ultraminiature package (ECSP2828-10)

#### **Functions**

- Constant current control ( $I_{OUT} = 100 \text{mA}$  at  $R_F = 2\Omega$ )
- Built-in thermal protection circuit
- Built-in reference voltage (0.2V typical)
- Built-in spark killer diode

#### **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		-0.3 to +8.0	V
Output voltage	V <sub>OUT</sub> max	OUT1, OUT2, OUT3	V <sub>CC</sub> + VSF	V
Input voltage	V <sub>IN</sub> max	IN1, IN2, IN3	-0.3 to +8.0	V
Ground pin source current	IGND	Per channel	400	mA
Allowable power dissipation	Pd max	When mounted on a circuit board *	450	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-40 to +150	°C

<sup>\*</sup> Specified circuit board :  $20.0 \times 10.0 \times 0.8 \text{mm}^3$ , paper-phenol

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#### SANYO Semiconductor Co., Ltd.

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

### **LB8681CL**

#### Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	VCC		2.2 to 7.5	V
High-level input voltage	V <sub>IH</sub>	IN1,IN2,IN3	1.8 to 7.5	V
Low-level input voltage	$V_{IL}$		-0.3 to 0.7	V

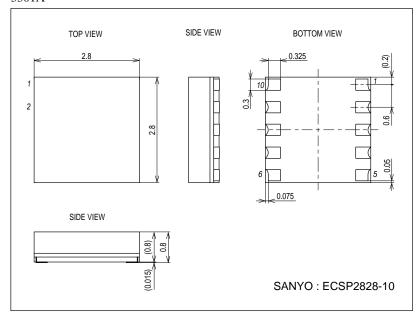
# **Electrical Characteristics** at Ta = 25°C, $V_{CC} = 3.3$ V

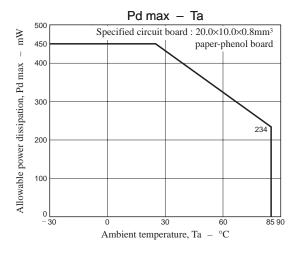
Davameter	Symbol	O and Millians	Ratings			11-4
Parameter		Conditions	min	typ	max	Unit
Supply current	I <sub>CC</sub> 0	IN1 = IN2 = IN3 = 0V			1	μΑ
	I <sub>CC</sub> 1	IN1, IN2, or IN3 = 3V		13.9	18	mA
Output saturation voltage	V <sub>OUT</sub> 1	IN1, IN2, or IN3 = 3V, I <sub>OUT</sub> = 100mA	100mA		0.32	V
	V <sub>OUT</sub> 2	IN1, IN2, or IN3 = 3V, I <sub>OUT</sub> = 200mA*		0.41	0.62	V
Output constant current	I <sub>OUT1</sub>	Between REF and GND : $2\Omega$	95	100	105	mA
	I <sub>OUT2</sub>	Between REF and GND : 1Ω*	190	200	210	mA
Input current	I <sub>IN</sub>	V <sub>IN</sub> = 3V		40	60	μΑ
Spark killer diode						
Reverse current	IS(leak)				1	μΑ
Forward voltage	VSF	I <sub>OUT</sub> = 200mA*			1.7	V

 $<sup>^{\</sup>star}$  Design guarantee: These characteristics are design targets and are not measured.

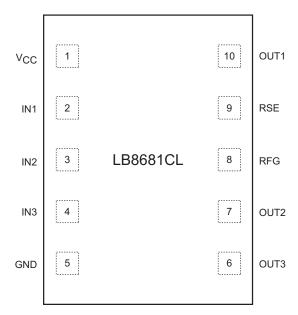
# **Package Dimensions**

unit: mm (typ) 3301A



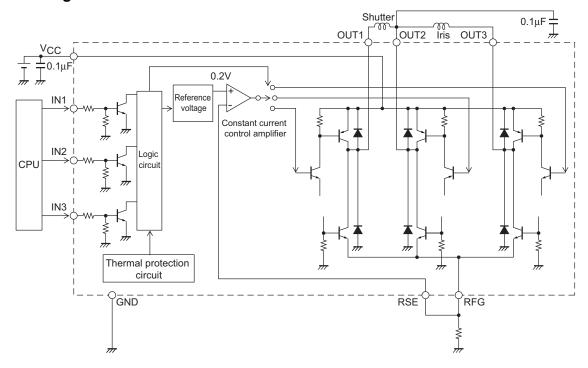


# **Pin Assignment**



Top View

# **Block Diagram**



[Constant current formula]  $I_{OUT} = 0.2 \div RF$ 

When  $V_{CC}$  is high, the  $0.01\mu F$  capacitor may be inserted between OUT and OUT.

#### **Truth Table**

Input		Output					
IN1	IN2	IN3	OUT1	OUT2	OUT3	Notes	
	Low	Low	-	-	-	Standby	
1	High	Low	High	Low	-	Shutter	Forward
Low	Low	High	Low	High	-		Reverse
	High	High	Low	High	-		
	Low	Low	-	-	-		Off
High	High	Low	-	Low	High	Aperture	Forward
	Low	High	-	High	Low		Reverse
	High	High	-	High	Low		

Note : "-" indicates the output off state. (high-impedance)

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